NSN 5962-00-134-1565

Memory Microcircuit - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5962-00-134-1565 **Body Length:** 0.785 inches **Body Width:** 0.280 inches **Body Height:** 0.180 inches **Maximum Power Dissipation Rating:** 450.0 milliwatts **Operating Tempurature Range:** -55.0/+125.0 degrees celsius Storage Tempurature Range: -65.0 to 150.0 degrees celsius **End Application:** Test station, guided missile remote controlsystem an/awm-23 **Features Provided:** Hermetically sealed and monolithic and positive outputs and high voltage **Inclosure Material:** Ceramic **Inclosure Configuration:** Dual-in-line **Output Logic Form:** Current-mode logic **Input Circuit Pattern:** 6 input **Terminal Surface Treatment:** Solder Voltage Rating And Type Per Characteristic: 40.0 volts power source **Time Rating Per Chacteristic:** 50.00 nanoseconds delay **Memory Device Type:** Diode matrix **Terminal Type And Quantity:** 16 printed circuit Shelf Life: N/a **Unit Of Measure: Demilitarization:**

Yes - demil/mli

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